# **MEMS Fabrication Techniques**

There are three basic building blocks in MEMS technology

## > Deposition (Additive Method) :

• Thin Film Deposition

## Etching (Subtractive Method) :

- Wet Etching
- Dry Etching

## > Patterning (Pattern Transfer Method) :

- Photo Lithography
- E-beam Lithography
- Nano-imprinting Lithography
- LIGA

# **MEMS Deposition Technology**

MEMS deposition technology can be classified in two groups:

#### > Deposition via physical reaction

- Physical Vapor Deposition (PVD)
- Casting

#### Deposition via chemical reaction

- Chemical Vapor Deposition (CVD)
- Electrodeposition
- Epitaxy
- Thermal oxidation

# **MEMS Deposition Technology**

Deposit thin film of material (mask) anywhere between a few nm to 100 micrometers onto substrate

- Physical: material placed onto substrate, techniques include sputtering and evaporation
- Chemical: stream of source gas reacts on substrate to grow product, techniques include chemical vapor deposition and atomic layer deposition
- **Substrates**: silicon, glass, quartz
- **Thin films**: polysilicon, silicon dioxide, silicon nitride, metals, polymers

# **MEMS Deposition Technology**



# Additive Methods: Thin Film Deposition

# Physical Vapor Deposition (PVD)

- Thermal Evaporation
- Sputtering

# Chemical Vapor Deposition (CVD)

- PECVD (Plasma Enhanced)
- LPCVD (Low Pressure)
- Electroplating
- Atomic Layer Deposition

#### **PVD:** Thermal Evaporation



• Low working pressure to increase mean free path

- Low surface damage
- Faster than sputtering
- Limited material

## **Additive Processes**



### **PVD:** Sputtering



- Based on Ion bombardment
- Unlimited material
- Possible surface damage
- Excellent adhesion
- Expensive



### Video: PVD Sputtering

銀嘉科技來自台灣是全球第一家以濺鍍方式將銀、銅、鈦等 金屬濺鍍於不織布上應用,開發出全新材料的公司, ingA公司名稱源自將純"銀"奈米化"加"入材料之中而來!

# **Additive Processes**

	Thermal Evaporation	Sputtering
Rate	Thousand atomic layers at a time	One atomic layer at a time
Choice of materials	Limited	Almost limited
Surface damage	Very low	Ionic bombardment damage
In-situ clearing	Not available	Can be easily done
Adhesion	Poor	Good
Uniformity	Difficult to control	Easy control
Film properties	Difficult to control	Can be controlled by pressure, bias and temperature
Step coverage		





### **Additive Processes: CVD**

Gaseous reactants are introduced into chamber at elevated temperatures.
Reactant reacts and deposits onto substrate

LPCVD (Low Pressure CVD),
 PECVD (Plasma Enhanced CVD)

CVD results depend on pressure, gas, and temperature

- Can be diffusion or reaction limited
- Varies from film composition, deposition rate and electrical and mechanical properties

#### **CVD:** Low Pressure

### • LPCVD



- < 10 Pa
- Excellent purity
- Low stress
- High temperature
- Low deposition rate

#### **CVD:** Plasma Enhanced

#### • PECVD



- Plasma helps reaction
- Low substrate temperature
- Good step coverage
- Chemical contamination

# Electroplating



- Various metal (Au, Ni, etc)
- Fast
- > 10 µm
- Hydrogen bubble generation
- Difficult for sub-µm features
- Needs seed layer

# **Electroplating: Video**



# **Atomic Layer Deposition**

#### Film thickness uniformity with different methods



#### Advantages:

excellent conformality

#### reproducibility

- large area uniformity
- accurate and easy film thickness control down to an atomic level

## **Atomic Layer Deposition: Movie**

#### Example of ALD coating process



#### Highly Flexible Photocatalytic Metal Oxide Structures Templated from Eggshell Membranes









Nature Materials submitted

### **Anti-Microbial Activity**

*E.coli* survival curves



Nature Materials submitted

# Metal Oxide Nanotubes: templating ES-fibers



Chemistry of Materials submitted

# **Mechatronics MEMS in Mechatronics**

